

**RQ3E100GN** 

# Nch 30V 21A Middle Power MOSFET

## Datasheet

V <sub>DSS</sub>	30V
R <sub>DS(on)</sub> (Max.)	11.7mΩ
I <sub>D</sub>	±21A
P <sub>D</sub>	15W

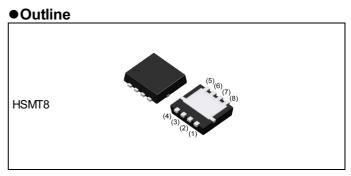
## Features

- 1) Low on resistance.
- 2) High power package (HSMT8).
- 3) Pb-free lead plating ; RoHS compliant
- 4) Halogen free

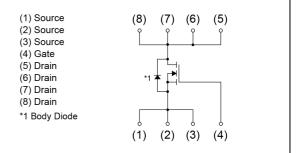
Application

Switching

5) 100% Rg and UIS tested.



#### Inner circuit



#### Packaging specifications

	Packing	Embossed Tape
	Reel size (mm)	330
Туре	Tape width (mm)	12
	Basic ordering unit (pcs)	3000
	Taping code	ТВ
	Marking	E100GN

## • Absolute maximum ratings (T<sub>a</sub> = 25°C ,unless otherwise specified)

Paramete	Symbol	Value	Unit	
Drain - Source voltage	V <sub>DSS</sub>	30	V	
Continuous durin current	$T_c = 25^{\circ}C$	۱ <sub>D</sub> *1	±21	А
Continuous drain current	$T_a = 25^{\circ}C$	I <sub>D</sub>	±10	А
Pulsed drain current	I <sub>DP</sub> *2	±40	А	
Gate - Source voltage	V <sub>GSS</sub>	±20	V	
Avalanche current, single pulse	I <sub>AS</sub> *3	10	А	
Avalanche energy, single pulse		E <sub>AS</sub> *3	7.6	mJ
Dower dissipation	P <sub>D</sub> <sup>*1</sup>	15	W	
Power dissipation	P <sub>D</sub> *4	2.0	W	
Junction temperature	Tj	150	°C	
Operating junction and storage t	T <sub>stg</sub>	-55 to +150	°C	

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## •Thermal resistance

Deremeter	Currence of	Values			Linit
Parameter	Symbol	Min.	Тур.	Max.	Unit
Thermal resistance, junction - case	R <sub>thJC</sub> *1	-	-	8.3	°C/W
Thermal resistance, junction - ambient	$R_{thJA}^{*4}$	-	-	62.5	°C/W

# • Electrical characteristics (T<sub>a</sub> = 25°C)

Devenantes	Queek el	Canditiana		Values		1.1
Parameter	Symbol Conditions		Min.	Тур.	Max.	Unit
Drain - Source breakdown voltage	$V_{(BR)DSS}$ $V_{GS} = 0V, I_D = 1mA$		30	-	-	V
Breakdown voltage temperature coefficient	$\frac{\Delta V_{(BR)DSS}}{\Delta T_j}$	$\frac{\Delta V_{(BR)DSS}}{\Delta T_{j}} I_{D} = 1mA$ referenced to 25°C		28	-	mV/°C
Zero gate voltage drain current	$I_{DSS}$ $V_{DS} = 24V, V_{GS} = 0V$		-	-	1	μA
Gate - Source leakage current	I <sub>GSS</sub>	$I_{GSS}$ $V_{GS} = \pm 20V, V_{DS} = 0V$		-	±100	nA
Gate threshold voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}$ , $I_D = 1mA$	1.2	-	2.5	V
Gate threshold voltage temperature coefficient	$\frac{\Delta V_{GS(th)}}{\Delta T_{j}}   I_{D} = 1 \text{mA}$ referenced to 25°C		-	-3.87	-	mV/°C
Static drain - source	<b>D</b> *5	V <sub>GS</sub> = 10V, I <sub>D</sub> = 10A	-	8.9	11.7	
on - state resistance	${\sf R}_{\sf DS(on)}^{*5}$	V <sub>GS</sub> = 4.5V, I <sub>D</sub> = 10A	-	12.0	20.0 mΩ	
Gate resistance	R <sub>G</sub>	R <sub>G</sub> f=1MHz, open drain		2.4	-	Ω
Forward Transfer Admittance	$ Y_{fs} ^{*5}$ $V_{DS} = 5V, I_D = 10A$		8	-	-	S

\*1 Tc =  $25^{\circ}$ C, Limited only by maximum temperature allowed.

\*2 Pw $\leq$ 10µs , Duty cycle $\leq$ 1%

\*3 L  $\simeq$  0.1mH, V\_{DD} = 15V, R\_G = 25 $\Omega$ , STARTING T\_j = 25°C Fig.3-1,3-2

- \*4 Mounted on a Cu board (40×40×0.8mm)
- \*5 Pulsed



# •Electrical characteristics (T<sub>a</sub> = 25°C)

Deremeter	Cumph of	Conditions		Linit		
Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit
Input capacitance	C <sub>iss</sub>	V <sub>GS</sub> = 0V	-	420	-	
Output capacitance	C <sub>oss</sub>	C <sub>oss</sub> V <sub>DS</sub> = 15V		120	-	pF
Reverse transfer capacitance	C <sub>rss</sub>	C <sub>rss</sub> f = 1MHz		32	-	
Turn - on delay time	t <sub>d(on)</sub> *5	$V_{DD} \simeq 15V, V_{GS} = 10V$	-	8.4	-	
Rise time	t <sub>r</sub> *5	I <sub>D</sub> = 5A	-	4.3	-	
Turn - off delay time	$t_{d(off)}^{*5}$ $R_L \simeq 3\Omega$		-	22.4	-	ns
Fall time	t <sub>f</sub> *5	R <sub>G</sub> = 10Ω	-	3.1	-	

# • Gate charge characteristics ( $T_a = 25^{\circ}C$ )

Deremeter	Sumbol	Conditions		Values			1 1
Parameter	Symbol			Min.	Тур.	Max.	Unit
<b>-</b>	$Q_g^{*5}$		V <sub>GS</sub> = 10V	-	7.9	-	
Total gate charge		V <sub>DD</sub> ≃ 15V		-	3.9	-	
Gate - Source charge	Q <sub>gs</sub> *5	I <sub>D</sub> = 10A	V <sub>GS</sub> = 4.5V	-	2.1	-	nC
Gate - Drain charge	Q <sub>gd</sub> *5			-	0.8	-	

# •Body diode electrical characteristics (Source-Drain) (T<sub>a</sub> = 25°C)

Deremeter	Sumbol	Conditiono		Unit		
Parameter	Symbol	ol Conditions –		Тур.	Max.	Unit
Continuous forward current	I <sub>S</sub>	T <sub>a</sub> = 25°C	-	-	1.67	А
Pulse forward current	$I_{SP}^{*2}$	$T_{a} = 25 C$	-	-	40	А
Forward voltage	$V_{SD}^{*5}$	V <sub>GS</sub> = 0V, I <sub>S</sub> = 1.67A	-	-	1.2	V
Reverse recovery time	t <sub>rr</sub> *5	I <sub>S</sub> = 10A, V <sub>GS</sub> =0V	-	18.5	-	ns
Reverse recovery charge	Q <sub>rr</sub> *5	di/dt = 100A/µs	-	8.9	-	nC

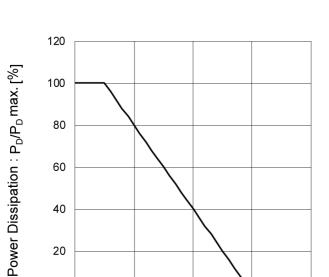
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0

0

50



# Fig.1 Power Dissipation Derating Curve

Fig.2 Maximum Safe Operating Area

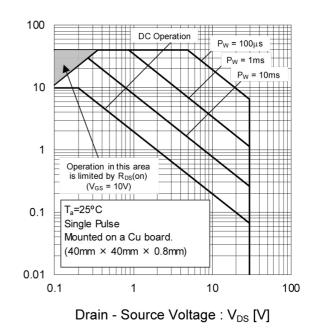


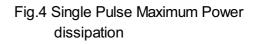
Fig.3 Normalized Transient Thermal Resistance vs. Pulse Width

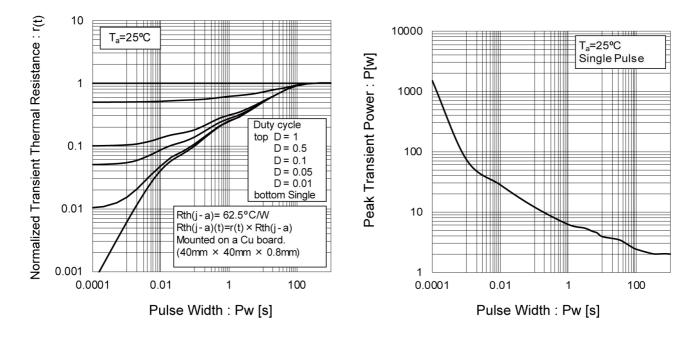
100

Junction Temperature : T<sub>i</sub> [°C]

150

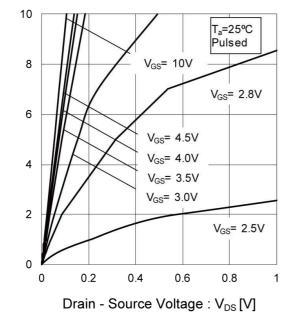
200





Drain Current : I<sub>D</sub> [A]





Drain Current : I<sub>D</sub> [A]

Fig.5 Typical Output Characteristics(I)

Fig.7 Breakdown Voltage vs. Junction Temperature

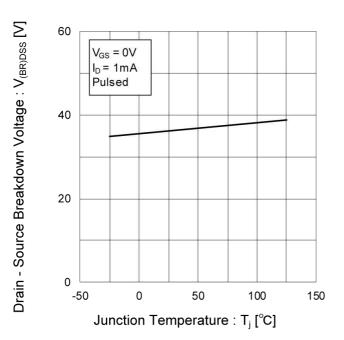


Fig.6 Typical Output Characteristics(II)

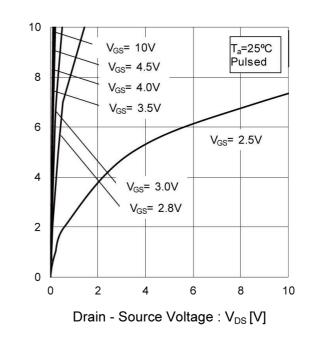
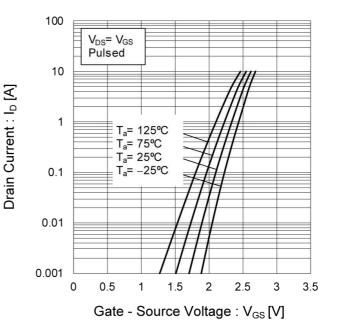


Fig.8 Typical Transfer Characteristics



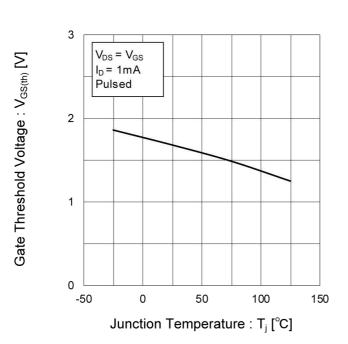
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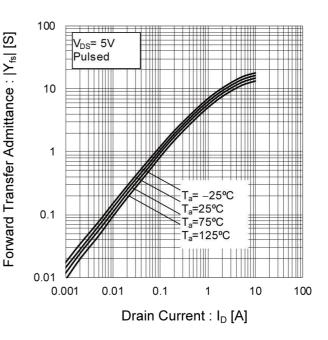


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## • Electrical characteristic curves



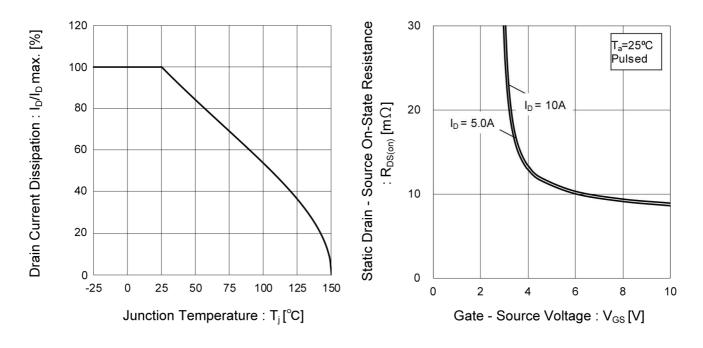
## Fig.9 Gate Threshold Voltage vs. Junction Temperature



## Fig.10 Forward Transfer Admittance vs. Drain Current

Fig.11 Drain Current Derating Curve

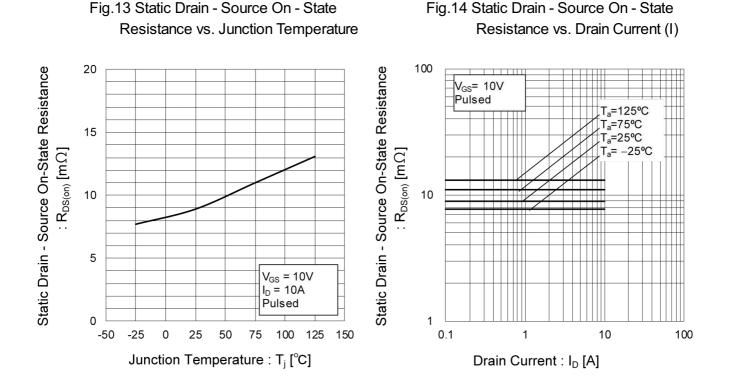
Fig.12 Static Drain - Source On - State Resistance vs. Gate Source Voltage



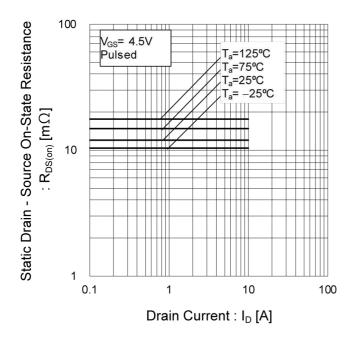
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## • Electrical characteristic curves



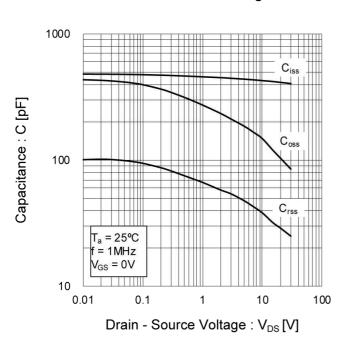
# Fig.15 Static Drain - Source On - State Resistance vs. Drain Current (II)



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## •Electrical characteristic curves



## Fig.16 Typical Capacitance vs. Drain - Source Voltage

Fig.17 Switching Characteristics

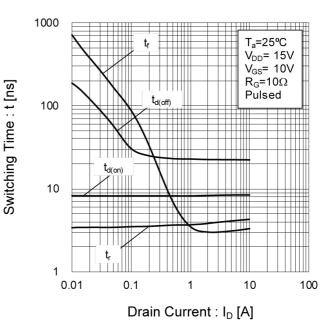


Fig.18 Dynamic Input Characteristics

Gate - Source Voltage : V<sub>GS</sub> [V]

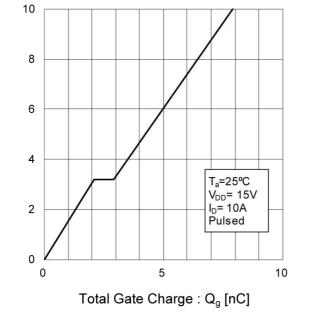
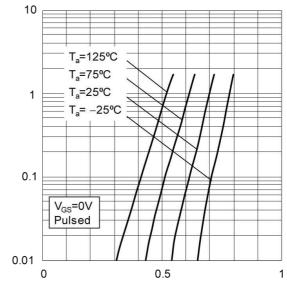


Fig.19 Source Current vs. Source Drain Voltage



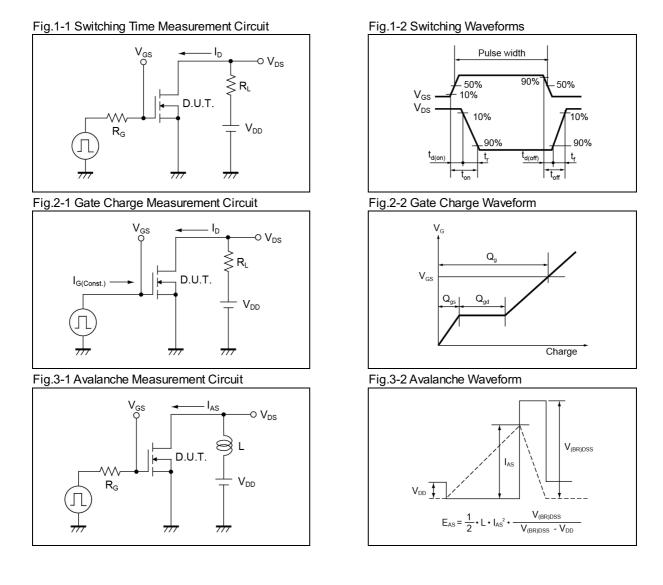
Source - Drain Voltage :  $V_{SD}$  [V]

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Source Current : I<sub>s</sub> [A]



#### Measurement circuits



#### Notice

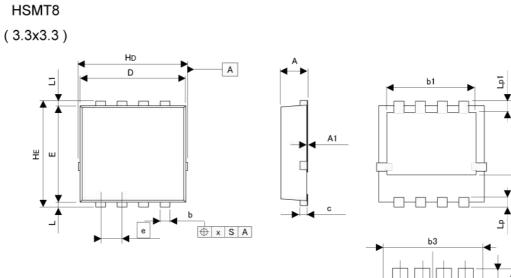
This product might cause chip aging and breakdown under the large electrified environment. Please consider to design ESD protection circuit.

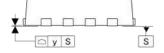
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## RQ3E100GN

#### Dimensions





Pattern of terminal position areas [Not a pattern of soldering pads]

DIM	MILIME	ETERS	INC	HES
	MIN	MAX	MIN	MAX
A	0.70	0.90	0.028	0.035
A1	0.00	0.05	0.000	0.002
b	0.27	0.37	0.011	0.015
b1	2.50	2.70	0.098	0.106
с	0.10	0.30	0.004	0.012
D	3.10	3.30	0.122	0.130
E	2.90	3.10	0.114	0.122
e	0.	65	0.0	26
HD	3.20	3.40	0.126	0.134
HE	3.20	3.40	0.126	0.134
L	0.07	0.25	0.003	0.010
L1	0.07	0.25	0.003	0.010
Lp	0.20	0.40	0.008	0.016
Lp1	0.25	0.45	0.010	0.018
Lp2	2.20	2.40	0.087	0.094
x	-	0.10		0.004
у	(#)	0.10		0.004
	MILIME	TERS	INC	HES
DIM	MIN	MAX	MIN	MAX
b2	521	0.47	) i (	0.019
b3	8 <b>7</b> 0	2.70		0.106
11	19 <b>-</b> 3	0.50	j e j	0.020
12	12	0.55	i u i	0.022

Dimension in mm/inches

13 14 2.40

3.40



0.094

0.134

# Notice

#### Precaution on using ROHM Products

1. Our Products are designed and manufactured for application in ordinary electronic equipments (such as AV equipment, OA equipment, telecommunication equipment, home electronic appliances, amusement equipment, etc.). If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, transport equipment, traffic equipment, aircraft/spacecraft, nuclear power controllers, fuel controllers, car equipment including car accessories, safety devices, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

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CLASSⅣ	CLASSIII	CLASSⅢ	CLASSI

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  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
- 4. The Products are not subject to radiation-proof design.
- 5. Please verify and confirm characteristics of the final or mounted products in using the Products.
- 6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
- 7. De-rate Power Dissipation depending on ambient temperature. When used in sealed area, confirm that it is the use in the range that does not exceed the maximum junction temperature.
- 8. Confirm that operation temperature is within the specified range described in the product specification.
- 9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

#### Precaution for Mounting / Circuit board design

- 1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
- 2. In principle, the reflow soldering method must be used on a surface-mount products, the flow soldering method must be used on a through hole mount products. If the flow soldering method is preferred on a surface-mount products, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

#### Precautions Regarding Application Examples and External Circuits

- 1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
- 2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

#### **Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of lonizer, friction prevention and temperature / humidity control).

#### Precaution for Storage / Transportation

- 1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl2, H2S, NH3, SO2, and NO2
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
- 2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
- 3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
- 4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

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A two-dimensional barcode printed on ROHM Products label is for ROHM's internal use only.

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When disposing Products please dispose them properly using an authorized industry waste company.

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